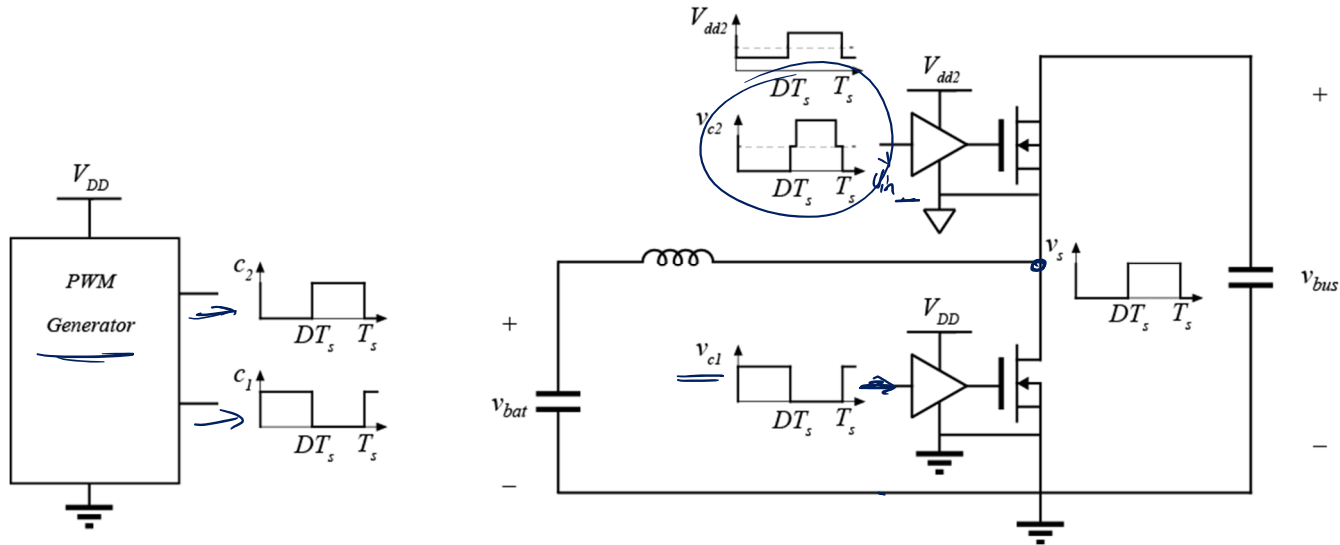
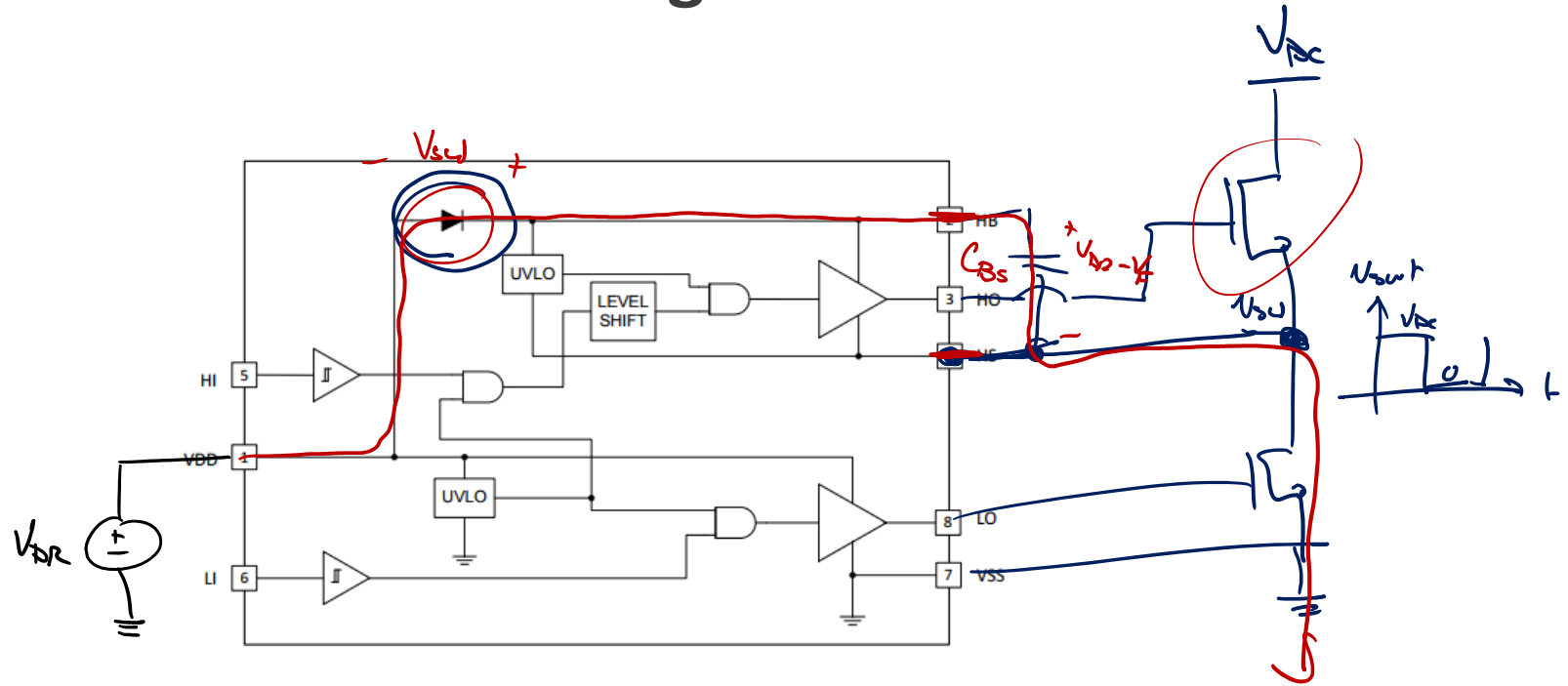


High Side Signal Ground

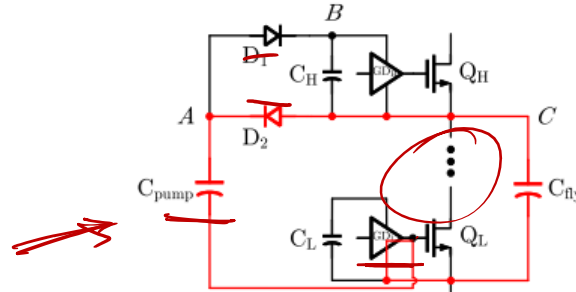
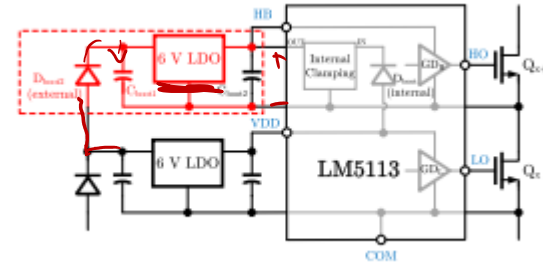
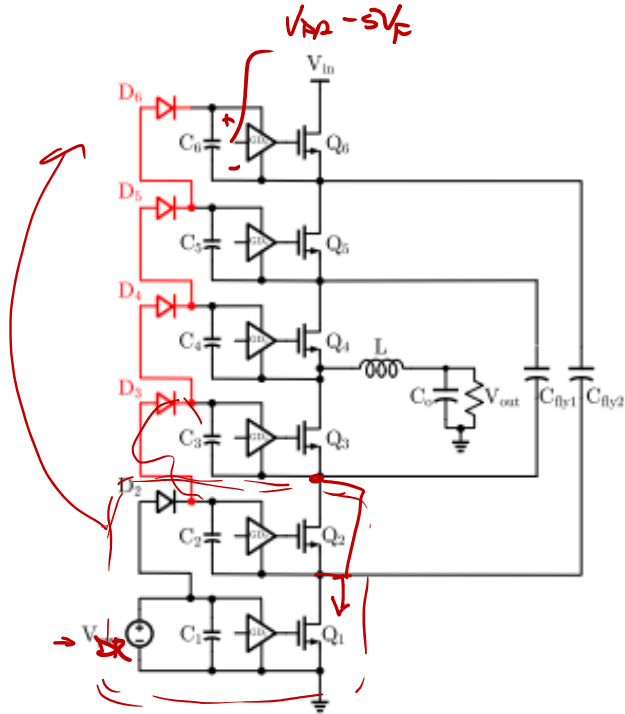


- Gate driver chip must implement v_{gs} waveforms
- Issue: source of Q_2 is not grounded

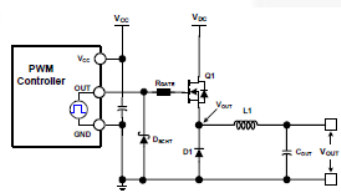
UCC27211a Internal Diagram



Cascaded Bootstrapping



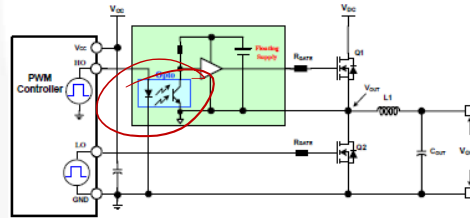
Direct Drive



Easiest high-side application the MOSFET and can be driven directly by the PWM controller or by a ground referenced driver, but it must meet two conditions, as follows:

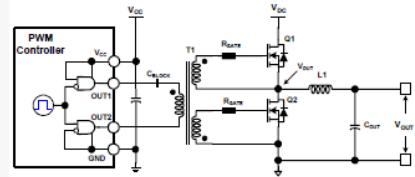
$$V_{CC} < V_{GS,MAX} \quad \text{and} \quad V_{DC} < V_{CC} - V_{GS,Miller}$$

Floating Supply Gate Drive



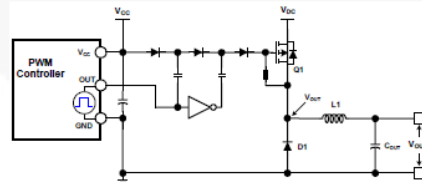
Cost impact of isolated supply is significant. Opto-coupler tends to be relatively expensive, limited in bandwidth, and noise sensitive.

Transformer Coupled Drive



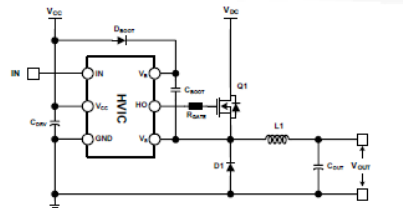
Gives full gate control for an indefinite period of time, but is somewhat limited in switching performance. This can be improved with added complexity.

Charge Pump Drive



The turn-on times tend to be long for switching applications. Inefficiencies in the voltage multiplication circuit may require more than low stages of pumping.

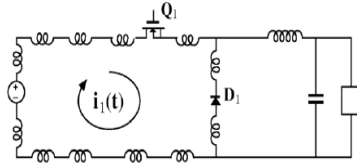
Bootstrap Drive



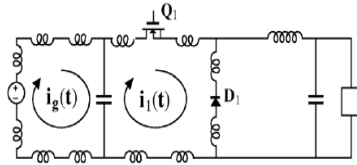
Simple and inexpensive with limitations; such as, the duty cycle and on-time are both constrained by the need to refresh the bootstrap capacitor. Requires level shift, with the associated difficulties.

Half Bridge Loop Inductance

Parasitic inductances of input loop explicitly shown:

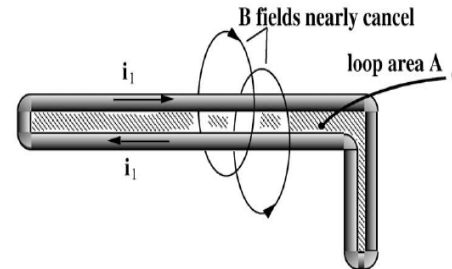
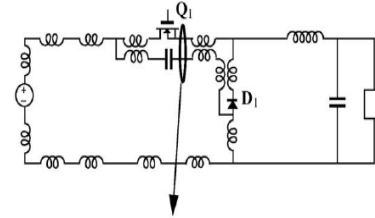


Addition of bypass capacitor confines the pulsating current to a smaller loop:

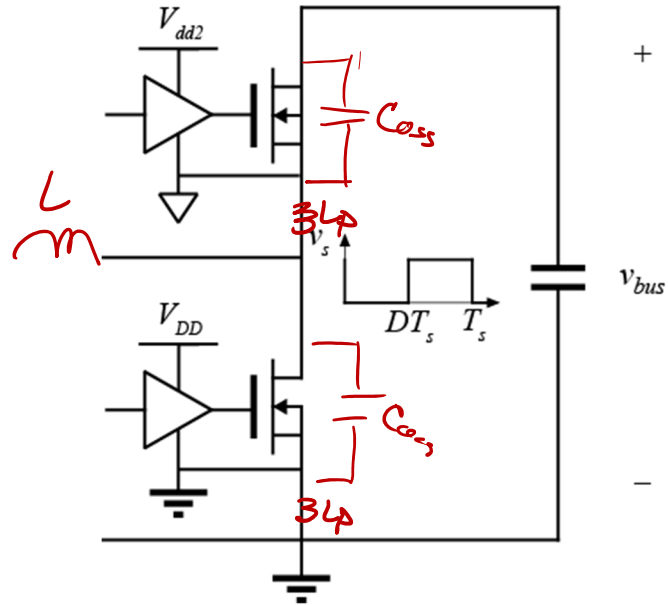


high frequency currents are shunted through capacitor instead of input source

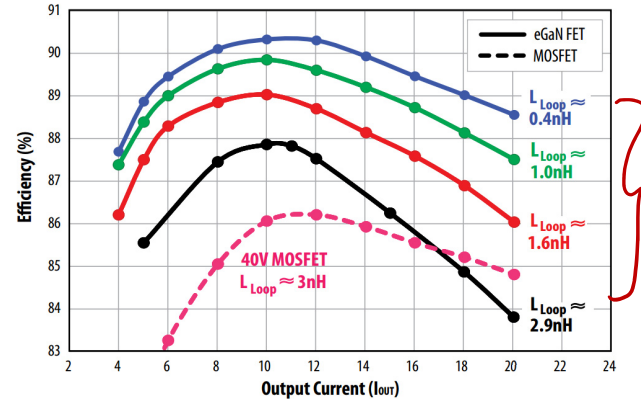
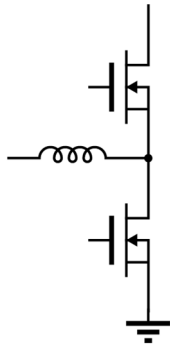
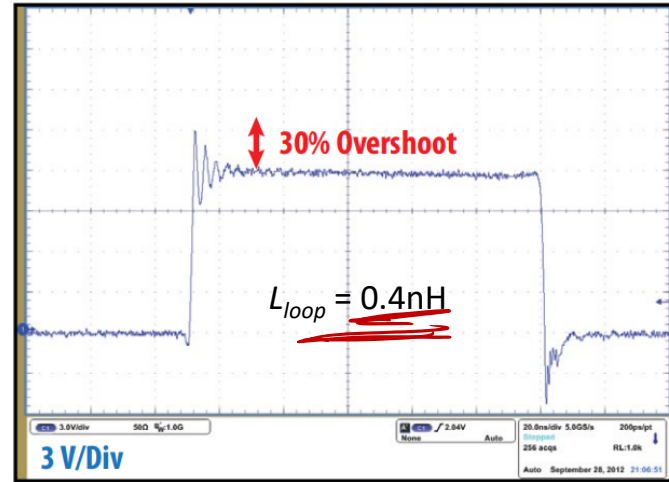
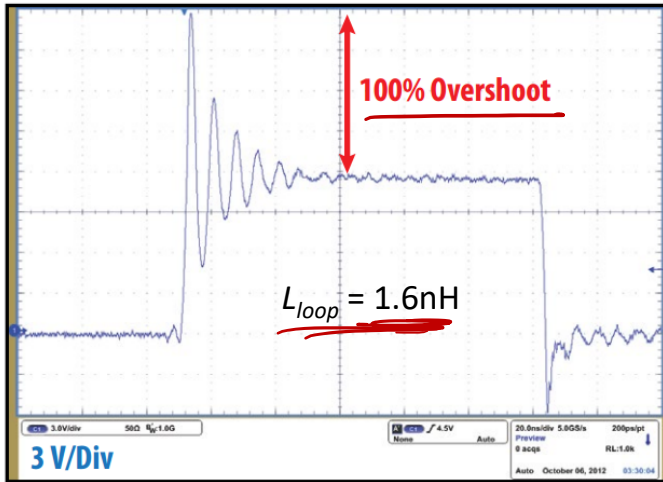
Even better: minimize area of the high frequency loop, thereby minimizing its inductance



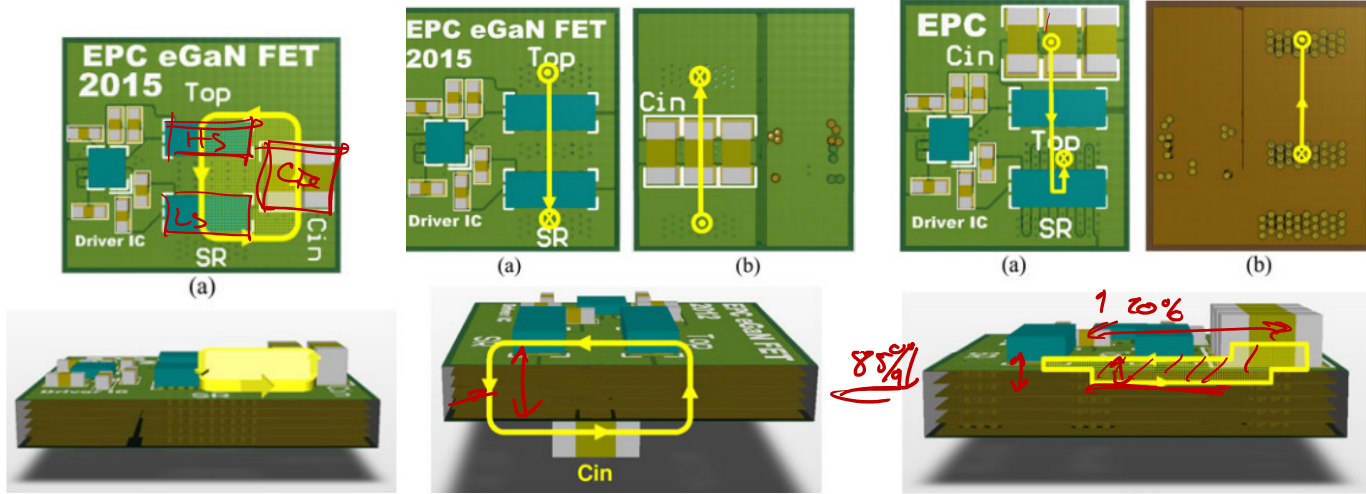
Bridge Layout



Effect of Loop Inductance



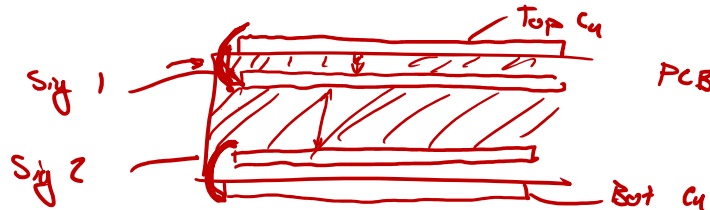
Half Bridge Layout: Another Example



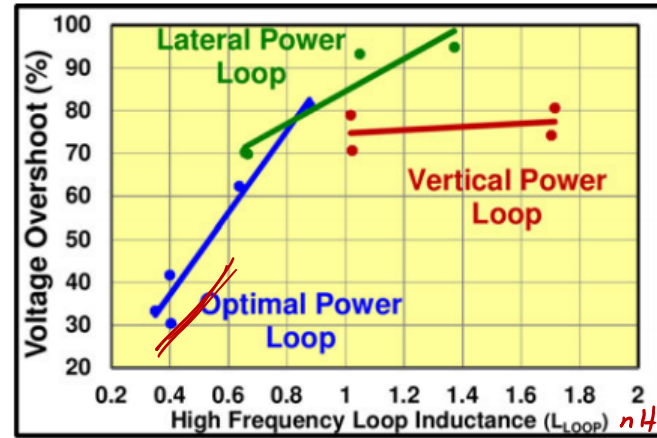
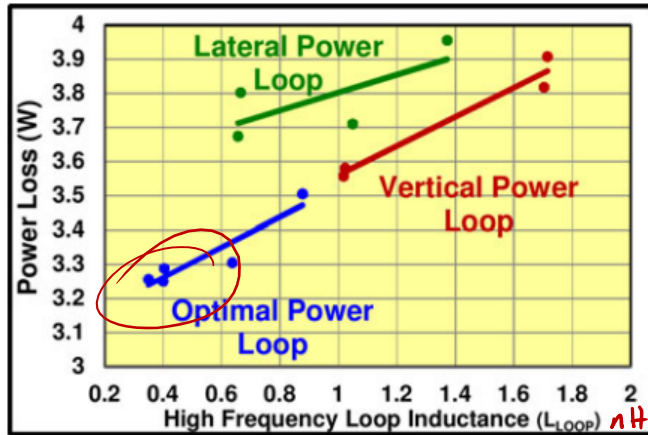
Lateral

Vertical

“Optimal”



Layout Impact Measurements



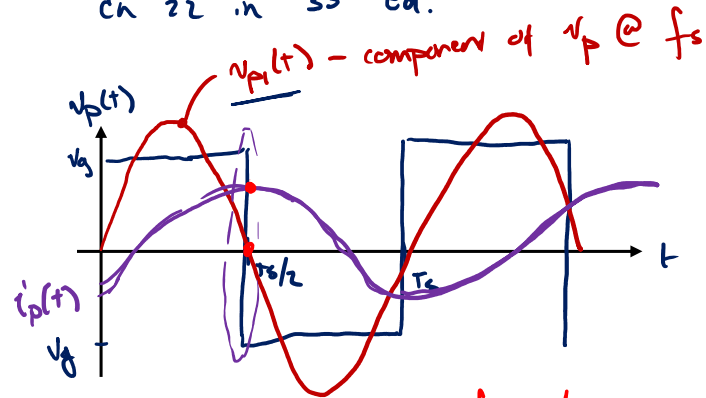
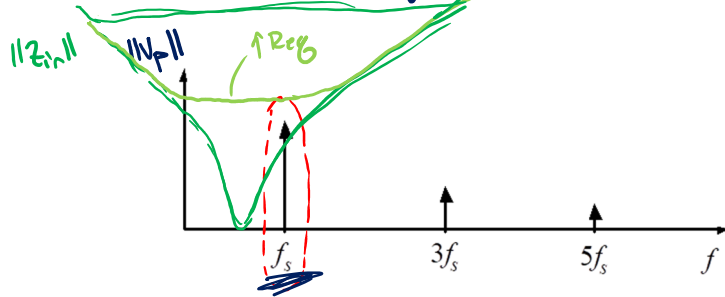
- Smallest Loop Area results in
 - Smaller overvoltage
 - Lower switching loss



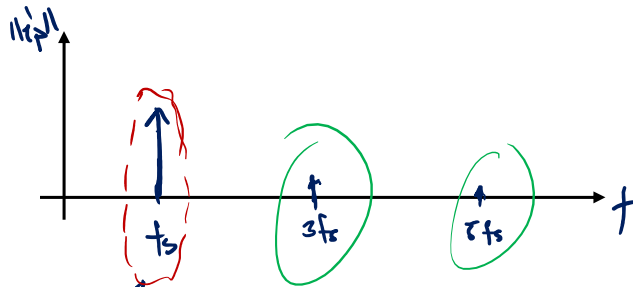
Sinusoidal Analysis (Ch 19)

(Fundamental Harmonic Analysis)

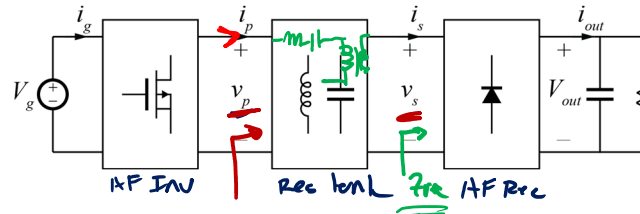
Fundamentals of Elec (2nd)
Ch 22 in 33rd Ed.



will lose exact ZUS information
- can check current polarity for possible ZUS



even more fundamental dominated
due to bandpass characteristics of
the tank



Zin
e.g. for SRC $Z_{in} = sL_r + \frac{1}{sC} + \frac{Z_{rec}}{n^2} \approx \text{Reg}$



Sinusoidal Analysis: Comments

- Generally most accurate when operating near resonance with a high Q
- Effective quality factor Q_e depends not only on resonant tank, but also on loading
- Analysis neglects switching intervals; can only predict where ZVS cannot be obtained

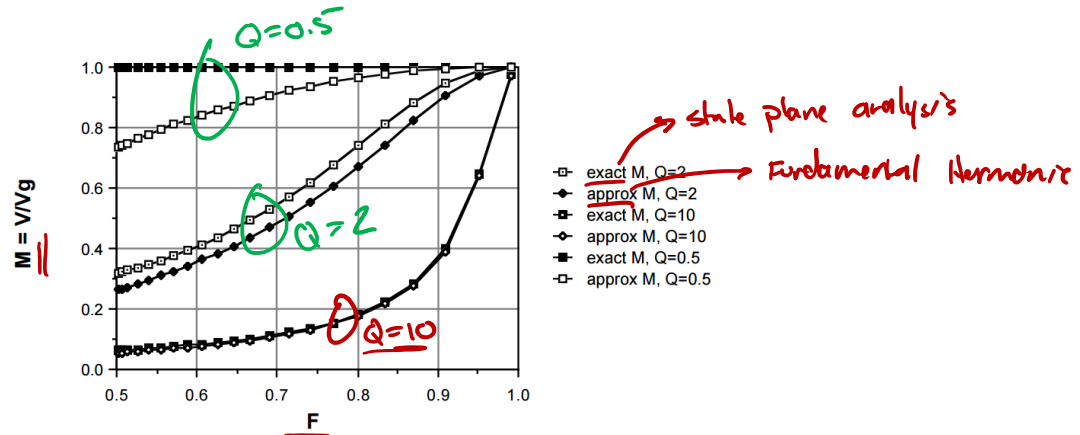
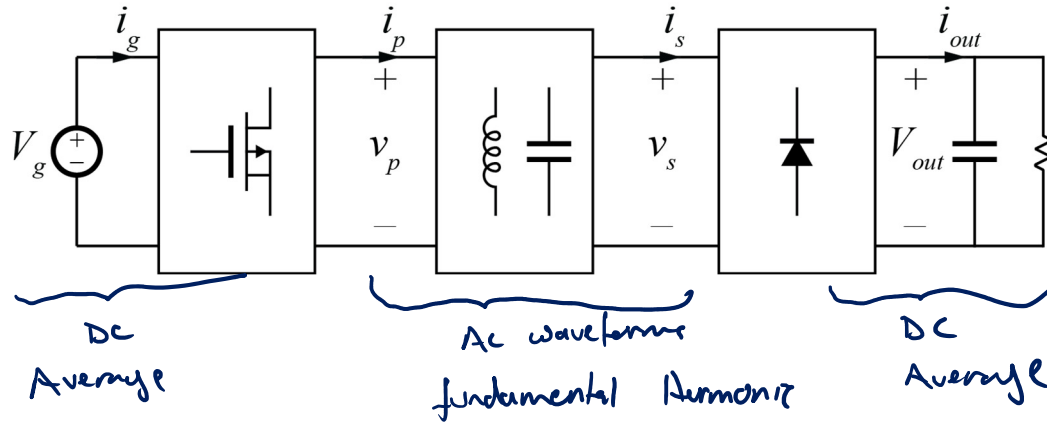




Fig. 2.14. Comparison of exact and approximate series resonant converter characteristics, below resonance.

AC Link Waveforms



$v_p(t) \rightarrow$ full/actual signal 
 $v_{p_1}(t) \rightarrow$ fundamental harmonic 
 $V_{p_1} \cos(\omega_s t + \phi_{v_p})$